### INTEGRATED CIRCUITS

## DATA SHEET

# **74LVT16245B**3.3V ABT 16-bit transceiver (3-State)

Pproduct specification Supersedes data of 1994 May 23 IC23 Data Handbook





### 3.3V 16-bit transceiver (3-State)

### 74LVT16245B

#### **FEATURES**

- 16-bit bidirectional bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

#### **DESCRIPTION**

The 74LVT16245B is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3V.

This device is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable ( $\overline{OE}$ ) input for easy cascading and a Direction (DIR) input for direction control.

### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER CONDITIONS $T_{amb} = 25^{\circ}C$		TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nBx or nBx to nAx	$C_L = 50pF;$ $V_{CC} = 3.3V$	1.9	ns
C <sub>IN</sub>	Input capacitance DIR, OE	$V_I = 0V \text{ or } 3.0V$	3	pF
C <sub>I/O</sub>	I/O pin capacitance	$V_{I/O} = 0V \text{ or } 3.0V$	9	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 3.6V	70	μΑ

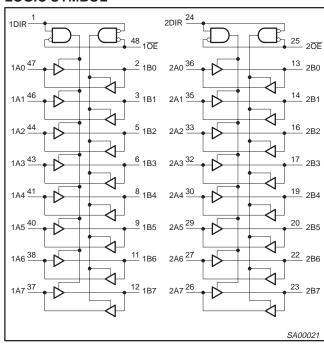
#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT16245B DL	VT16245B DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT16245B DGG	VT16245B DGG	SOT362-1

#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 24	nDIR	Direction control input
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	nA0 – nA7	Data inputs/outputs (A side)
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	nB0 – nB7	Data inputs/outputs (B side)
25, 48	nŌĒ	Output enable input (active-Low)
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42 V <sub>CC</sub>		Positive supply voltage

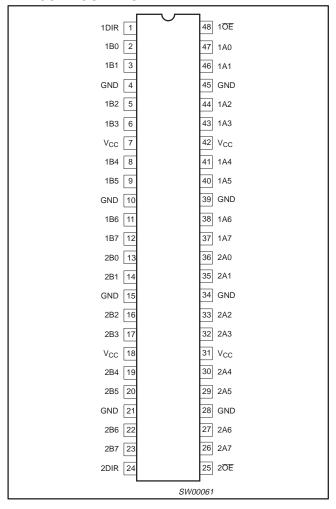
#### LOGIC SYMBOL



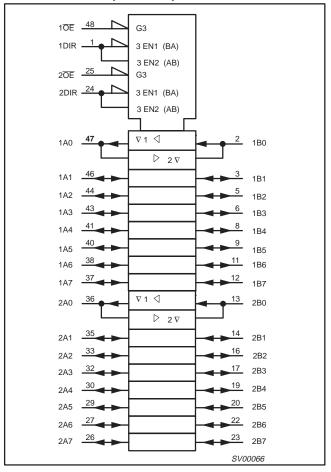
### 3.3V 16-bit transceiver (3-State)

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### **PIN CONFIGURATION**



### LOGIC SYMBOL (IEEE/IEC)



### **FUNCTION TABLE**

INP	UTS	INPUTS/0	DUTPUTS			
nOE	n <del>OE</del> nDIR		nBx			
L	L	nAx = nBx	Inputs			
L	Н	Inputs	nBx = nAx			
Н	Х	Z	Z			

H = High voltage level

= Low voltage level

X = Don't care Z = High Impedance "off" state

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### ABSOLUTE MAXIMUM RATINGS1,2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
lok	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V
	DC output ourrent	Output in Low state	128	A
lout	DC output current	Output in High state	-64	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

#### NOTES:

### **RECOMMENDED OPERATING CONDITIONS**

CVMDOL	DADAMETED	LIM	LIMITS		
SYMBOL	PARAMETER	MIN	MAX	UNIT	
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V	
VI	Input voltage	0	5.5	V	
V <sub>IH</sub>	High-level input voltage	2.0		V	
V <sub>IL</sub>	Input voltage		0.8	V	
I <sub>OH</sub>	High-level output current		-32	mA	
I <sub>OL</sub>	Low-level output current		32	mA	
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	]	
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C	

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

<sup>3.</sup> The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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#### DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT
				MIN	TYP <sup>1</sup>	MAX	V V V μA μA μA μA μA
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$		-0.85	-1.2	V	
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V <sub>CC</sub> -0.2	V <sub>CC</sub>		
$V_{OH}$	High-level output voltage	V <sub>CC</sub> = 2.7V; I <sub>OH</sub> = -8mA	2.4	2.5		V	
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.3		
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.07	0.2	
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 24mA			0.3	0.5	
$V_{OL}$	Low-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA			0.25	0.4	V
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 32mA			0.3	0.5	
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 64mA	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 64mA			0.55	
		$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND			0.1	±1	
		V <sub>CC</sub> = 0 or 3.6V; V <sub>I</sub> = 5.5V	Control pins		0.1	10	
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> = 3.6V; V <sub>I</sub> = 5.5V	3.6V; V <sub>I</sub> = 5.5V		0.1	20	μА
		$V_{CC} = 3.6V$ ; $V_I = V_{CC}$	I/O Data pins <sup>4</sup>		0.5	10	
		$V_{CC} = 3.6V; V_{I} = 0$	1		0.1	-5	
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μА
		$V_{CC} = 3V; V_I = 0.8V$		75	135		
$I_{HOLD}$	Bus Hold current A or B outputs <sup>6</sup>	$V_{CC} = 3V; V_I = 2.0V$		-75	-135		μΑ
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
$I_{EX}$	Current into an output in the High state when V <sub>O</sub> > V <sub>CC</sub>	V <sub>O</sub> = 5.5V; V <sub>CC</sub> = 3.0V			75	125	μΑ
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC} \le 1.2V$ ; $V_O = 0.5V$ to $V_{CC}$ ; $V_I = GNE$ OE/ $\overline{OE} = Don't$ care		40	±100	μА	
I <sub>CCH</sub>		$V_{CC} = 3.6V$ ; Outputs High, $V_I = GND$ or $V_{CC}$ , $I_{O} = 0$			0.07	0.12	
I <sub>CCL</sub>	Quiescent supply current	$V_{CC} = 3.6V$ ; Outputs Low, $V_I = GND$ or $V_{CC}$ , $I_{O} = 0$			4.7	6	mA
I <sub>CCZ</sub>	1	V <sub>CC</sub> = 3.6V; Outputs Disabled; V <sub>I</sub> = GNE		0.07	0.12		
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at $V_{CC}$ -0.6V Other inputs at $V_{CC}$ or GND	/,		0.1	0.2	mA

- NOTES:

  1. All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.

  2. This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND

  3. This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T<sub>amb</sub> = 25°C only.

  4. Unused pins at V<sub>CC</sub> or GND.

  5. I<sub>CCZ</sub> is measured with outputs pulled to V<sub>CC</sub> or GND.

  6. This is the bus hold overdrive current required to force the input to the opposite logic state.

- 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

### 3.3V 16-bit transceiver (3-State)

### 74LVT16245B

#### **AC CHARACTERISTICS**

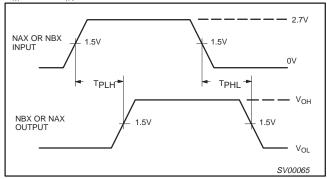
GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF;  $R_L$  = 500 $\Omega$ ;  $T_{amb}$  = -40°C to +85°C.

			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	Vcc	c = 3.3V +0	.3V	V <sub>CC</sub> = 2.7V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nBx or nBx to nAx	1	1.0 1.0	1.9 1.7	3.3 3.3	3.5 3.5	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.0 1.0	2.8 2.8	4.5 4.1	5.3 5.1	ns
t <sub>PHZ</sub>	Output disable time from High and Low Level	2	1.5 1.5	3.2 3.0	5.1 4.6	5.7 4.6	ns

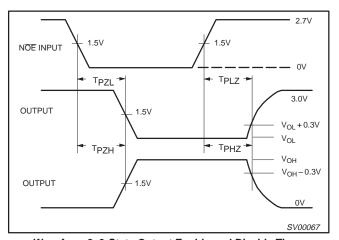
#### NOTE:

#### **AC WAVEFORMS**

 $V_M = 1.5V$ ,  $V_{IN} = GND$  to 2.7V



**Waveform 1. Input to Output Propagation Delays** 



Waveform 2. 3-State Output Enable and Disable Times

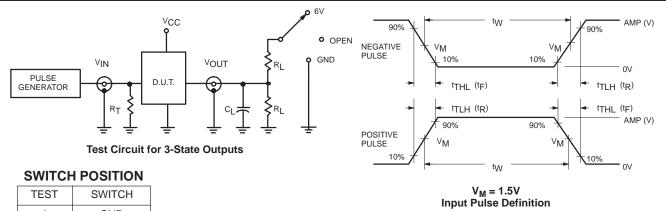
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<sup>1.</sup> All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

### 3.3V 16-bit transceiver (3-State)

### 74LVT16245B

### **TEST CIRCUIT AND WAVEFORMS**



TEST	SWITCH
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND
$t_{PLZ}/t_{PZL}$	6V
$t_{PLH}/t_{PHL}$	open

### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = \quad \text{Termination resistance should be equal to $Z_{OUT}$ of pulse generators.}$ 

EAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
FAMILY	Amplitude	Rep. Rate	t <sub>W</sub>	$t_{R}$	t <sub>F</sub>
74LVT16	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

SW00003

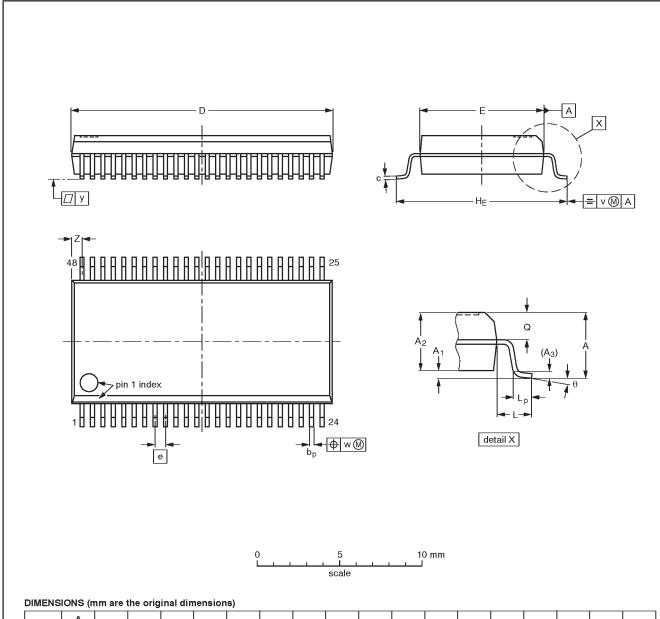
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### 3.3V ABT 16-bit transceiver (3-State)

### 74LVT16245B

### SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

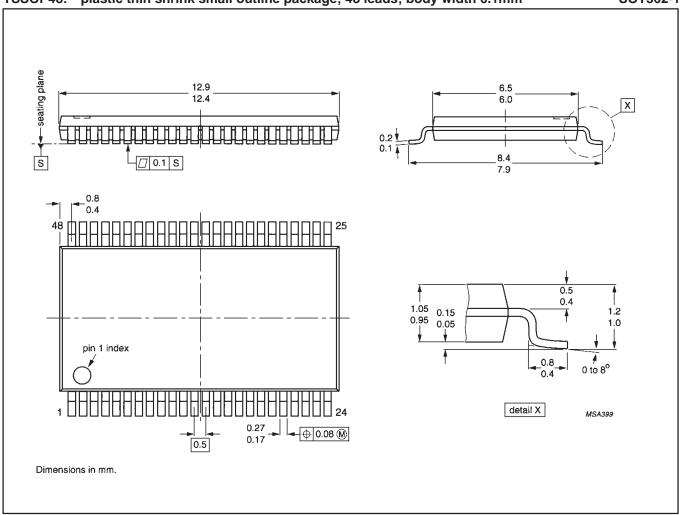
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT370-1		MO-118AA			<del>93-11-02</del> 95-02-04	

### 3.3V ABT 16-bit transceiver (3-State)

### 74LVT16245B

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm SOT362-1



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### 3.3V ABT 16-bit transceiver (3-State)

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

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